V<sub>RRM</sub> Qc  $I_F(\leq 160^{\circ}C) = 6$ = 1.39 V

# **SiC SBD P3D06006T2 650V SiC Schottky Diode**

### **Features**

- Qualified to AEC-Q101
- Ultra-Fast Switching
- Zero Reverse Recovery Current
- High-Frequency Operation
- Positive Temperature Coefficient on V<sub>F</sub>
- High Surge Current
- 100% UIS tested

### TO-220-2

Cathode	1
Anode	2



### **Standards Benefits**

- Improve System Efficiency
- Reduction of Heat Sink Requirement
- Essentially No Switching Losses
- Parallel Devices Without Thermal Runaway



## **Application**

- Consumer SMPS
- Boost Diodes in PFC or DC/DC Stages
- AC/DC Converters



## **Order Information**

Part Number	Package	Marking
P3D06006T2	TO-220-2	P3D06006T2

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# 1. Maximum Ratings

At T<sub>J</sub>= 25°C, unless specified otherwise

Parameter	Symbol	Value	Unit	Test condition
Repetitive Peak Reverse Voltage	$V_{RRM}$	650	V	T <sub>C</sub> = 25℃
Surge Peak Reverse Voltage	V <sub>RSM</sub>	650	V	T <sub>C</sub> = 25°C
DC Blocking Voltage	$V_R$	650	V	T <sub>C</sub> = 25°C
Forward Current	I <sub>F</sub>	23 12 6	A	$T_C$ = 25°C $T_C$ = 125°C $T_C$ = 160°C
Repetitive Peak Forward Surge Current	I <sub>FRM</sub>	36 16	А	$T_C$ = 25°C, $t_p$ = 10ms $T_C$ = 125°C, $t_p$ = 10ms
Non-Repetitive Forward Surge Current	I <sub>FSM</sub>	45 37	А	$T_C$ = 25°C, $t_p$ = 10ms $T_C$ = 125°C, $t_p$ = 10ms
Non-Repetitive Forward Surge Current	I <sub>F, MAX</sub>	464 432	А	$T_C$ = 25°C, $t_p$ = 10 $\mu$ s $T_C$ = 125°C, $t_p$ = 10 $\mu$ s
Power Dissipation	P <sub>tot</sub>	98	W	T <sub>C</sub> = 25°C
Operating Junction and Storage Temperature	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C	
TO-220 Mounting Torque M3 Screw	T <sub>orq</sub>	1 8.8	Nm Ibf-in	

## 2. Thermal Characteristics

Parameter	Symbol	Values	Unit
Thermal Resistance from Junction to Case	$R_{\theta JC}$	1.53	°C/W

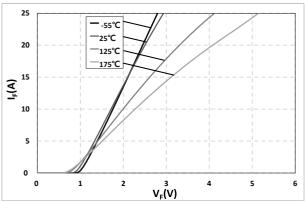
## 3. Electrical Characteristics

At T<sub>J</sub>= 25°C, unless specified otherwise

		Values					
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test condition	
Forward Voltage	V	,	1.39	1.6		I <sub>F</sub> = 6A, T <sub>J</sub> = 25℃	
Forward Voltage	V <sub>F</sub>	/	1.65	/	V	I <sub>F</sub> = 6A, T <sub>J</sub> = 175°C	
Payarca Current	_	,	3.8	30	110	V <sub>R</sub> = 650V, T <sub>J</sub> = 25°C	
Reverse Current	I <sub>R</sub>	/	255	40	μΑ	V <sub>R</sub> = 650V, T <sub>J</sub> = 175°C	
Total Capacitance	c		271			$V_R = 0V$ , $T_J = 25$ °C f= 1MHz	
			31	/	рF	V <sub>R</sub> = 200V, T <sub>J</sub> = 25°C f= 1MHz	
			25			V <sub>R</sub> = 400V, T <sub>J</sub> = 25°C f= 1MHz	
Total Capacitive Charge	Q <sub>C</sub>	/	15.6	/	nC	$V_R = 400V, I_F = 6A$ $T_J = 25^{\circ}C$	
Capacitance Stored Energy	E <sub>C</sub>	/	2.01	/	μЈ	V <sub>R</sub> = 400V	

## 4. Typical Performance

At T<sub>J</sub>= 25°C, unless specified otherwise



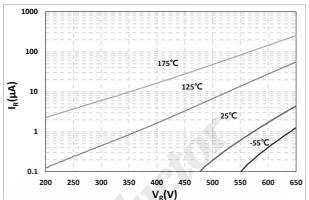
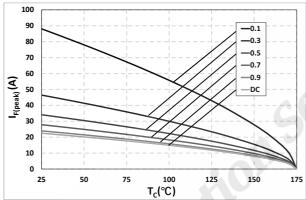


Fig. 1 Typical Forward Characteristics  $I_F = f(V_F); T_J = -55^{\circ}C, 25^{\circ}C, 125^{\circ}C, 175^{\circ}C$ 

Fig. 2 Reverse Characteristics  $I_R=f(V_R)$ ;  $T_J=-55^{\circ}C$ , 25°C, 125°C, 175°C



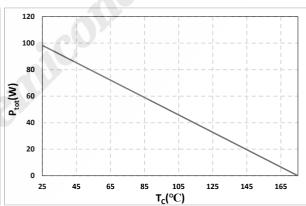
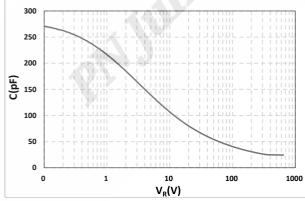


Fig. 3 Current Derating

Fig. 4 Typical Power Derating  $P_{tot} = f(T_C)$ 



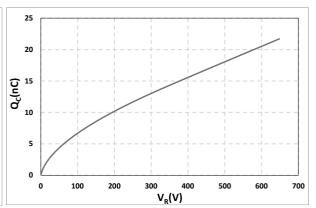


Fig. 5 Typical Total Capacitance  $C=f(V_R)$ 

Fig. 6 Typical Total Capacitive Charge  $Q_C = f(V_R)$ 

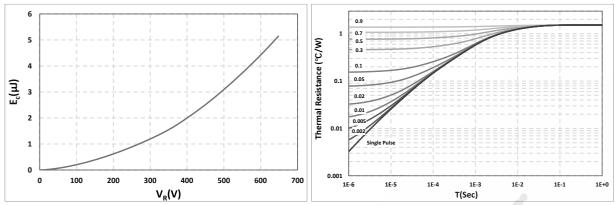
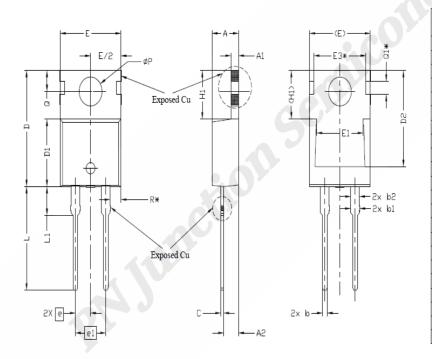


Figure 7. Capacitance Stored Energy  $E_C = f(V_R)$ 

Figure 8. Transient Thermal Impedance

# 5. Package Outlines



SYMBOL		NOTES			
STMBUL	MIN.	NOM.	MAX.	NOTES	
Α	4.24	4.44	4.64		
A1	1.15	1.27	1.40		
A2	2.30	2.48	2.70		
b	0.70	0.80	0.90		
b1	1.20	1.55	1.75		
b2	1.20	1.45	1.70		
С	0.40	0.50	0.60		
D	14.70	15.37	16.00	4	
D1	8.82	8.92	9.02		
D2	12.63	12.73	12.83	5	
Е	9.96	10.16	10.36	4,5	
E1	6.86	7.77	8.89	5	
E3*		8.70REF.			
е					
e1		5.08BSC			
H1	6.30	6.45	6.60	5,6	
L	13.47	13.72	13.97		
L1	3.60	3.80	4,00		
ØP	3.75	3.84	3.93		
Q	2.60	2.80	3.00		
Q1*					
R*		1.82REF.			

Drawing and dimensions